

Standard Laminate SiP Module

 Series/Type:
 R078 (WL1801) / D7021

 Ordering code:
 B30911D7021Y918

Date: Version: 2014-12-9 1.3

© EPCOS AG 2014. Reproduction, publication and dissemination of this publication, enclosures hereto and the information contained therein without EPCOS' prior express consent is prohibited.



#### **Standard Laminate SiP Module**

# B30911D7021Y918 R078 (WL1801) / D7021

# 1 Overview

This document details the specifications and features of R078 (WL1801) / D7021 SiP module. The R078 (WL1801) / D7021 SiP module is based on Texas Instruments WL1801 IC, specifically WL180x Data Sheet version 1.2, such that the SiP module specification is subject to any subsequent changes in applicable Texas Instruments documentation and software.

The R078 (WL1801) / D7021 contains the WL1801 SoC, 2.4GHz SPDT switch, 2.4GHz band pass filter / diplexer and necessary passive components for WLAN in a highly integrated solution.

### 1.1 Features

- WLAN on a single chip provides universal connectivity in small PCB footprint.
- Provides efficient direct connection to battery by employing several integrated switched mode power supplies (DC2DC).
- Based on 45nm CMOS technology using proven core technology.
- Seamless integration with TI OMAP<sup>™</sup> Application Processors.
- WLAN core software and hardware are compatible with prior WL127x and WL128x offerings, for smooth migration to Device.
- SDIO for WLAN.
- Downloadable patches and firmware enables new features to be added for all functional block's.
- Temperature detection and compensation mechanism ensures minimal variation in the RF performance over the entire temperature range.

## 1.2 Applications

Mobile phone and mobile computer device applications.

### **1.3 General Description**

The R078 (WL1801) / D7021 is a highly integrated WLAN device that forms a complete standalone communication system. The WL1801 is a highly integrated single-chip CMOS (45-nm process) incorporates the core functionality of the WL1271/3 and WL1281/3 devices.

The device is the 8th-generation WLAN device from Texas Instruments. As such, the WL1801 is based upon proven core technology and complements the TI integrated devices for connectivity portfolio.

R078 (WL1801) / D7021 is ideal for use in mobile phone and mobile computer device applications due to its low current, small area and cellular phone coexistence-friendly features.



### **Standard Laminate SiP Module**

## 1.4 Terms and abbreviations

BPF – Band-Pass Filter FE – Front-End (refers to FE IC and BPF) GND - Ground IC – Integrated Circuit I/O - Input/Output interfaces LDO - Low Drop-Out (voltage regulator) PCB - Printed Circuit Board Q - Quality factor RF – Radio Frequency RX - Receive SiP - System in Package SoC - System on Chip TX – Transmit Vbat - Battery Voltage VIO – external pre-existing 1.8V IO power supply WLAN – Wireless Local Area Network

## **1.5 Reference documents**

■ Texas Instruments WL180x\_Data\_Manual\_Rev\_1\_2.pdf

B30911D7021Y918 R078 (WL1801) / D7021

# **⊗TDK**

# Complementary wireless module WLAN

# **Standard Laminate SiP Module**

# B30911D7021Y918

R078 (WL1801) / D7021

1	OV	ERVIEW	2
	1.1	Features	2
	1.2	APPLICATIONS	2
	1.3	GENERAL DESCRIPTION	2
	1.4	TERMS AND ABBREVIATIONS	3
	1.5	REFERENCE DOCUMENTS	3
2	FUN	NCTIONAL BLOCK FEATURES	5
	2.1	FUNCTIONAL BLOCK DIAGRAM	5
	2.2	WLAN FEATURES	6
3	DET	TAILED DESCRIPTION	7
	3.1	HOST INTERFACES	7
	3.2	CLOCKS AND POWER MANAGEMENT	7
	3.3	WLAN FUNCTIONAL BLOCK	11
	3.4	TERMINAL ASSIGNEMENTS	12
	3.5	TERMINAL FUNCTIONS	13
4	DES	SIGN GOAL SPECIFICATIONS	19
	4.1	GENERAL CHIP REQUIREMENTS AND OPERATION	19
	4.2	WLAN RF Performance	22
	4.3	INTERFACE TIMING CHARACTERISTICS	25
	4.4	PACKAGE MECHANICAL DRAWING	27
	4.5	SCHEMATIC	28
5	LEA	AD-FREE PRODUCT STATUS	29
6	REG	COMMENDED REFLOW PROFILE	30
7	PAC	CKING INFORMATION	31
8	REV	VISION HISTORY	34
D	ISPLAY	Y OF ORDERING CODES FOR EPCOS PRODUCTS	34



### **Standard Laminate SiP Module**

# B30911D7021Y918 R078 (WL1801) / D7021

# 2 Functional Block Features

## 2.1 Functional Block Diagram

Figure 2-1 shows a high-level view of R078 (WL1801) / D7021 along with its various configurations. The flexibility of the R078 (WL1801) / D7021 based on WL1801 enables easy integration with various host-system topologies.

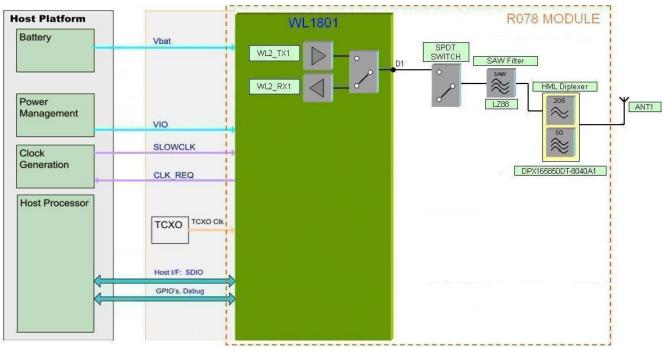


Figure 2-1 High-Level System Diagram



### **Standard Laminate SiP Module**

B30911D7021Y918 R078 (WL1801) / D7021

## 2.2 WLAN Features

- Integrated 2.4GHz power amplifiers for complete WLAN solution
- WLAN MAC Baseband Processor and RF transceiver IEEE802.11b/g/n compliant
- WLAN 2.4GHz SISO (20 / 40 MHz channels).
- Baseband Processor
  - IEEE Std 802.11b/g data rates and IEEE Std 802.11n data rates with 20 or 40 MHz SISO.
- Fully calibrated system. No production calibration required.
- Medium-Access Controller (MAC)
  - Embedded ARM<sup>™</sup> Central Processing Unit (CPU)
  - Hardware-Based Encryption/Decryption Using 64-, 128-, and 256-Bit WEP, TKIP or AES Keys,
  - Supports requirements for Wi-Fi Protected Access (WPA and WPA2.0) and IEEE Std 802.11i [Includes Hardware-Accelerated Advanced-Encryption Standard (AES)]
  - Designed to work with IEEE Std 802.1x
- 2.4GHz Radio
- Internal LNA, PA and RF switch
  - Supports: IEEE Std 802.11b, 802.11g and 802.11n
  - Supports 4 bit SDIO host interface, including high speed (HS) and V3 modes



**Standard Laminate SiP Module** 

B30911D7021Y918 R078 (WL1801) / D7021

# **3** Detailed Description

## 3.1 Host Interfaces

#### 3.1.1 WLAN SDIO Transport Layer

The SDIO is the host interface for WLAN. The interface between the host and the D7021 uses an SDIO interface and supports a maximum clock rate of 50MHz.

The Device SDIO also supports the following features of the SDIO V3 specification:

- 4 bit data bus
- Synchronous and Asynchronous In-Band-Interrupt
- Default and High-Speed (50MHz) timing
- Sleep/wake commands

SDIO timing specifications are given in specification section at end of document.

### 3.2 Clocks and Power Management

#### 3.2.1 Slow Clock / RTC clock

The slow clock is a free-running clock of 32.768 KHz which is supplied from an external clock source. It is connected to the RTC\_CLK pin and is a digital square-wave signal in the range of 0-1.8V nom.

#### 3.2.2 Fast Clock System

#### 3.2.2.1 Fast clock using external crystal

The devices incorporate an internal crystal oscillator circuit for supporting a cost optimized crystal based fast clock scheme. Connection is as shown:

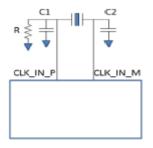


Figure 3-1 XTAL Connection

C1 = C2. Typically 8 - 22pF. Refer to Crystal manufacturer's recommendations. R = 390K ohm (+/- 5% tolerance).



B30911D7021Y918

R078 (WL1801) / D7021

**Complementary wireless module WLAN** 

### **Standard Laminate SiP Module**

## 3.2.2.2 Fast Clock using external oscillator

CLK\_IN\_P is the main system fast clock and must meet the specifications as described in "Fast clock specifications" at the end of this document.

The clock must be one of the specified frequencies and the device incorporates an internal mechanism to detect this. The clock can be AC or DC coupled, sine or square wave.

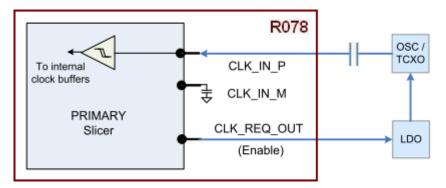
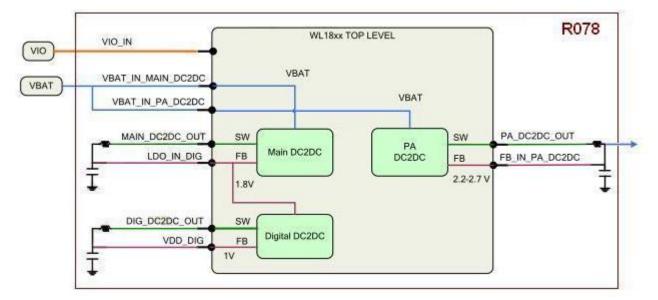


Figure 3-2 Fast Clock Block Diagram

#### 3.2.3 Power Management

#### 3.2.3.1 Block Diagram - internal DC2DC's

The Device incorporates three internal DC2DC's (switched-mode power supplies) to provide efficient internal and external supplies, derived from Vbat.



#### Figure 3-3 Internal DC2DC's



#### **Standard Laminate SiP Module**

R078 (WL1801) / D7021

#### 3.2.4 Reset / Power up system

After Vbat and VIO are fed to Device and while WLAN\_EN are de-asserted (LOW), the device is in Shutdown state.

While in Shutdown state all functional blocks, internal DC2DC's and LDO's will be disabled. The power supplied to the functional blocks is cut off.

When one of the two signals WLAN\_EN are asserted (High) a Power On Reset (POR) is performed. Stable Slow Clock, VIO and Vbat are pre-requisites for successful POR.

#### 3.2.4.1 Chip Top-level Power Up Sequence

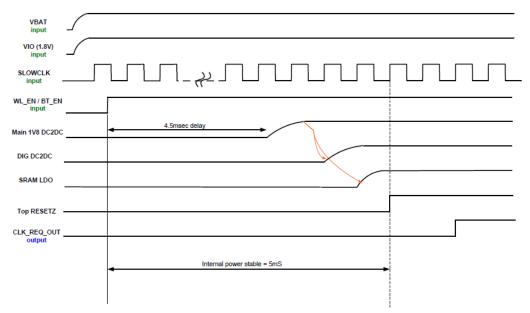


Figure 3-4 Chip Top-level Power Up Sequence



**Standard Laminate SiP Module** 

B30911D7021Y918 R078 (WL1801) / D7021

#### 3.2.4.2 WLAN Power Up Sequence

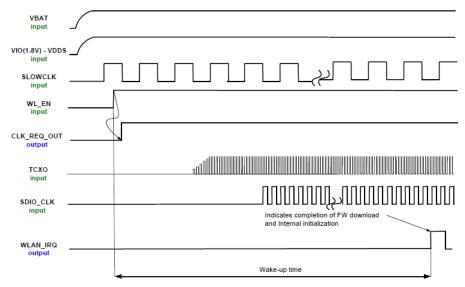


Figure 3-5 WLAN Power Up Sequence



#### **Standard Laminate SiP Module**

# B30911D7021Y918 R078 (WL1801) / D7021

## 3.3 WLAN Functional Block

#### 3.3.1 WLAN MAC

R078 (WL1801) / D7021 MAC implements the IEEE standard 802.11 MAC sub-layer using both dedicated hardware and embedded firmware. The MAC hardware implements real-time functions, including access protocol management, encryption and decryption.

#### 3.3.2 WLAN Baseband Processor

R078 (WL1801) / D7021 baseband processor implements the IEEE 802.11b/g/n PHY sub layers and has been optimized to perform well in conditions of high multipath and noise.

#### 3.3.3 WLAN RF Radio

R078 (WL1801) / D7021 WLAN radio is a highly integrated radio processor designed for 802.11b/g/n applications, including internal front-end PA's.

#### 3.3.4 WLAN RF Configuration and Power Options

The R078 (WL1801) / D7021 includes RF switch, band pass filter and diplexer for complete WLAN (SISO) RF system.

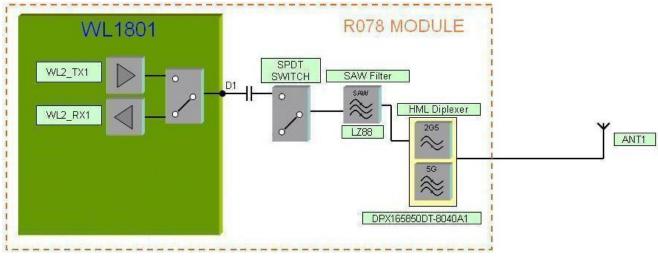


Figure 3-6 R078 (WL1801) / D7021 SISO configuration

#### 3.3.4.1 SISO configuration (WL1801 device)

The diagram above shows WLAN pins in standard SISO application.

# **公TDK**

## **Complementary wireless module WLAN**

# B30911D7021Y918

**Standard Laminate SiP Module** 

# R078 (WL1801) / D7021

## 3.4 Terminal Assignements

The view is from top side:

In		IS Tro	m top s	siae:	Е	F	G	н	J	к	L	м	N	Р		
12	GND	NU	GND	VIO	GND	GND	GND	GND	NU	NU	NU	NU	GND	GND	12	DIGITAL
11	GND	NU	GND	GND	GND	SDIO_D2_ WL	SDIO_CLK _WL	GND	NU	GND	NU	GND	GND	NU	11	RF
10	GND	NU	GND	NU	GND	SDIO_D3_ WL	SDIO_D0_ WL	GND	DC2DC_R EQ_MODE _SOC	CLK_REQ _OUT	GND	GND	GND	GND	10	Power
9	GND	GND	GND	NU	GND	SDIO_CM D_WL	SDIO_D1_ WL	GND	SLOW_CL K	NU	NU	GND	GND	NU	9	GND
8	NU	GND	NU	NU	GND	GND	GND	WS_BT_W	COEX_M WS_FRAM E_SYNC	NU	NU	GND	GND	NU	8	CLOCK
7	GND	GND	NU	GND	GND	COEX_M WS_ACTI VE	RX_SW_F EM_WL	COEX_M WS_RX_P RI	NU	NU	GND	GND	GND	NU	7	DIGITAL High Speed
6	NU	GND	PBIAS_TE STP_W	GND	GND	DC2DC_R EQ_OUT_ SOC	WLAN_IR Q	NU	GPIO_2	NU	NU	GND	GND	NU	6	Not Used
5	GND	GND	PDET_TE STM_W	GND	GND	GND	WLAN_EN _SOC	FEM_PA_ EN_WL	NU	GPIO_1	GND	GND	GND	GND	5	
4	GND	GND	NU	GND	NU	NU	NU	NU	NU	GPIO_3	GND	VBAT1	VBAT2	VBAT3	4	
3	11bg_ANT _1	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	3	
2	GND	GND	GND	GND	GND	CLK_IN_P	CLK_IN_M	GND	GND	GND	GND	GND	GND	GND	2	
1	GND	GND	GND	GND	GND	GND	GND	GND	PA_DC2D C_IN	C_OUT	GND	GND	GND	GND	1	
	A	В	С	D	E	F	G	н	J	к	L	М	N	Р	-	
							To	n vi								

Top view

**Figure 3-7 Terminal Assignements** 



## **Standard Laminate SiP Module**

# B30911D7021Y918

R078 (WL1801) / D7021

# 3.5 Terminal Functions

Pin names and pin numbers in bracket apply to WSP pin out.

Table 3-3 Terminal Functions											
Module Pin Name (WSP Pin Name)		I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description					
WLAN pins: I/O signals	,										
SDIO_CLK_WL (SDIO_CLK_WL)	G11 (E11)	IN	HiZ	HiZ		WLAN SDIO clock. Must be driven by the host.					
SDIO_CMD_WL(SDIO_CMD_WL)	F9 (D8)	IN	HiZ	HiZ		WLAN SDIO command in. Host must pull up.					
SDIO_D0_WL (SDIO_D0_WL)	G10 (E10)	I/O	HiZ	HiZ		WLAN SDIO data bit 0. Host must pull up.					
SDIO_D1_WL (SDIO_D1_WL)	G9 (E9)	I/O	HiZ	HiZ		WLAN SDIO data bit 1. Host must pull up.					
SDIO_D2_WL (SDIO_D2_WL)	F11 (D11)	I/O	HiZ	HiZ		WLAN SDIO data bit 2. Host must pull up.					
SDIO_D3_WL (SDIO_D3_WL)	F10 (D10)	I/O	HiZ	PU		WLAN SDIO data bit 3. Changes state to PU at WL_EN assertion for card detect. Later disabled by the SW during init. Host must pull up.					
WLAN_IRQ (IRQ_WL)	G6 (E3)	OUT	PD	Drive 0		SDIO available, interrupt out. Active high. To use WL_RS232_TX/RX lines, need to pull up with 10K resistor.					
GPIO_1 (GPIO1)	K5 (H1)	I/O	PD	PD		Option: WL_RS232_TX (when IRQ_WL = 1 at power up)					
GPIO_2 (GPIO2)	J6 (H2)	I/O	PD	PD		Option: WL_RS232_RX (when IRQ_WL = 1 at power up)					
GPIO_3 (UART_DBG_WL)	K4 (G4)	OUT	PU	PU		WLAN logger Option: GPIO3					
FEM_PA_EN_WL (GPIO13)	H5 (F2)					NC					
RX_SW_FEM_WL (SW_CTRL_BG_IO1)	G7 (F3)					NC					
PBIAS_TESTP_W (PABIAS_OUT_FEM_TESTP_WL)		ANA				NC					
PDET_TESTM_W (PDET_IN_FEM_TESTM_WL)	C5 (C6)	ANA				NC					
WLAN Pins: RF antenna		<b>_</b>		-							
11bg_ANT_1	A3	RF				WLAN BG RX and TX 50Ω input and output. No external matching required.					
Clock pins											
CLK_IN_P	. ,	ANA				FREF/TCXO input for all functional blocks					
CLK_IN_M	G2 (E5)	ANA				Connect to GND					
SLOW_CLK (RTC_CLK)		ANA				Sleep clock 32.768 kHz					
CLK_REQ_OUT	K10 (K11)	OUT	PD	PD		Request external fast clock NC if not used.					

# Complementary wireless module WLAN

# B30911D7021Y918

# **Standard Laminate SiP Module**

## R078 (WL1801) / D7021

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state		Buffer Type [mA]	Description
Enable pins				1	1	
WLAN_EN_SOC (WLAN_EN)	G5 (E1)	IN	PD	PD		High = enable
Power management pins		T	1	1	r.	
VBAT1	M4	POW				Battery voltage
VBAT2	N4	POW				Battery voltage
VBAT3	P4	POW				Battery voltage
	D12	POW				1.8V I/O power supply
PA_DC2DC_IN PA_DC2DC_OUT	J1 K1	POW POW				PA power supply input, with internal PA_DC2DC connect to pin PA_DC2DC_OUT K1. DC2DC output for PA supply, with internal PA_DC2DC connect to pin PA_DC2DC_IN J1.
DC2DC_REQ_OUT_SOC (NU)	F6 (D3)					NC
DC2DC_REQ_MODE_SOC (NU)	J10 (J10)					NC
Co-existence signals			1	1	1	
COEX_MWS_RX_PRI	H7 (G5)		PU	PU		General purpose IO.
(COEX_MWS_UART_RX)						NC if not used.
COEX_MWS_BT_WL_TX_O	H8 (G7)		PU	PU		General purpose IO.
(COEX_MWS_UART_TX)			<b>D</b> U	DU		NC if not used.
COEX_MWS_ACTIVE (COEX_MWS_PRE_TX)	F7 (G8)		PU	PU		General purpose IO. NC if not used.
COEX_MWS_FRAME_SYNC	J8 (H7)		PU	PU		General purpose IO.
(COEX_MWS_FRAME_SYNC)	,					NC if not used.
Not used pins				-1		
NU	A6 (A4)					NC
NU	A8					NC
NU	B10 (G11)					NC
NU	B11 (G9)					NC
NU	B12 (H11)					NC
NU	C4 (F9)					NC
NU	C7 (F8)					NC
NU	C8 (F11)					NC
NU	D8 (F10)					NC
NU	D9 (E8)					NC
NU	D10 (B11)					NC
NU	E4 (E2)					NC
NU	F4 (E7)					NC
NU	G4 (F7)					NC
NU	H4 (G6)					NC
NU	H6 (G2)					NC
NU	J4 (F6)					NC
NU	J5 (H3)					NC
NU	J7 (H5)					NC

# Complementary wireless module WLAN

# B30911D7021Y918

R078 (WL1801) / D7021

# **Standard Laminate SiP Module**

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball	I/O Type	Shut Down state	Buffer Type [mA]	Description
NU	n <b>o.)</b> J5 (H3)				NC
NU	J7 (H5)				NC
NU	J11 (G10)				NC
NU	J12 (J8)				NC
NU	K6 (J4)				NC
NU	K7 (K4)				NC
NU	K8 (K5)				NC
NU	K9 (J7)				NC
NU	K12 (K8)				NC
NU	L6 (H6)				NC
NU	L8 (L7)				NC
NU	L9 (K7)				NC
NU	L11 (L11)				NC
NU	L12 (M10)				NC
NU	M12 (M9)				NC
NC	P6 (M7)				NC
NC	P7 (M5)				NC
NU	P8 (L5)				NC
NU	P9 (M6)				NC
NU	P11 (K6)				NC
Ground pins	[ ] ] [ ] ] ]				
GND	A1	GND			
GND	A2	GND			
GND	A4	GND			
GND	A5	GND			
GND	A7	GND			
GND	A9	GND			
GND	A10	GND			
GND	A11	GND			
GND	A12	GND			
GND	B1	GND			
GND	B2	GND			
GND	B3	GND			
GND	B4	GND			
GND	B5	GND			
GND	B6	GND			
GND	B7	GND			
GND	B8	GND			
GND	B9	GND			

# Complementary wireless module WLAN

# B30911D7021Y918 R078 (WL1801) / D7021

# **Standard Laminate SiP Module**

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Buffer Type [mA]	Description
GND	C1	GND			
GND	C2	GND			
GND	C3	GND			
GND	C9	GND			
GND	C10	GND			
GND	C11	GND			
GND	C12	GND			
GND	D1	GND			
GND	D2	GND			
GND	D3	GND			
GND	D4	GND			
GND	D5	GND			
GND	D6	GND			
GND	D7	GND			
GND	D11	GND			
GND	E1	GND			
GND	E2	GND			
GND	E3	GND			
GND	E5	GND			
GND	E6	GND			
GND	E7	GND			
GND	E8	GND			
GND	E9	GND			
GND	E10	GND			
GND	E11	GND			
GND	E12	GND			
GND	F1	GND			
GND	F3	GND			
GND	F5	GND			
GND	F8	GND			
GND	F12	GND			
GND	G1	GND			
GND	G3	GND			
GND	G8	GND			
GND	G12	GND			
GND	H1	GND			
GND	H2	GND			
GND	H3	GND			
GND	H9	GND			

### **Complementary wireless module WLAN**

## B30911D7021Y918

R078 (WL1801) / D7021

### **Standard Laminate SiP Module**

#### I/O Default Buffer Description Module Pin Name Module Shut (WSP Pin Name) Pin No. Down after Туре Туре (WSP ball POR state [mA] no.) GND H10 GND GND H11 GND GND H12 GND GND J2 GND GND J3 GND GND K2 GND GND K3 GND GND K11 GND GND L1 GND GND L2 GND GND GND L3 GND L4 GND GND L5 GND GND L7 GND GND L10 GND GND M1 GND GND М2 GND GND M3 GND GND M5 GND GND Μ6 GND GND Μ7 GND GND M8 GND GND Μ9 GND GND M10 GND GND M11 GND GND N1 GND GND N2 GND GND N3 GND GND N5 GND GND N6 GND N7 GND GND GND N8 GND GND N9 GND GND N10 GND GND N11 GND GND N12 GND P1 GND GND GND P2 GND GND P3 GND



# B30911D7021Y918

# Standard Laminate SiP Module

# R078 (WL1801) / D7021

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)		Down	after	Buffer Type [mA]	Description
GND	P5	GND				
GND	P10	GND				
GND	P12	GND				



B30911D7021Y918

**Complementary wireless module WLAN** 

**Standard Laminate SiP Module** 

# R078 (WL1801) / D7021

# 4 Design Goal Specifications

#### Section Disclaimer

This Specification is based upon the Texas Instruments WL180x Data Sheet version 1.2, and is subject to any subsequent changes in applicable Texas Instruments documentation and software.

Any parameter marked TBD indicates that this is yet to be determined by TDK design/testing. Any parameter marked TBC indicates that this is yet to be determined in an update of Texas Instruments documentation.

## 4.1 General Chip Requirements and Operation

All parameters are measured as follows unless stated otherwise: VIO=1.8V

#### 4.1.1 Absolute Maximum Ratings <sup>(1)</sup>

			Value	Unit		
VBAT <sup>(2)</sup>			-0.5 to 5.5 <sup>(4)</sup>	V		
VIO			-0.5 to 2.1	V		
Input voltage to Analog	oins <sup>(3)</sup>		-0.5 to 2.1	V		
Input voltage to all other	Input voltage to all other pins					
Operating ambient temp	erature range		-40 to +85 <sup>(5)</sup>	°C		
ESD Stress Voltage (6)	Human Body Model <sup>(7)</sup>	RF pins	>500	V		
		Other	>1000	V		
	Charged Device Model <sup>(8)</sup>	RF pins	>300	V		
		Other	>250	V		

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The following signals are from the VBAT group: VBAT1, VBAT2, VBAT3

(3) Analog pins: 11bg\_ANT\_1.

(4) 5.5V up to 10s cumulative in 7 years. 5V cumulative to 250s, 4.8V cumulative to 2.33 years - all includes charging dips and peaks.

(5) Operating free-air temperature range. The device can be reliably operated for 7 years at  $T_{ambient}$  of 85°C, assuming 25% active mode and 75% sleep mode (15,400 cumulative active power-on hours).

(6) Electrostatic discharge (ESD) to measure device sensitivity/immunity to damage caused by electrostatic discharges into the device.

(7) Level listed is the passing level per ANSI/ESDA/JEDEC JS-001. JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process, and manufacturing with less than 500V HBM is possible if necessary precautions are taken. Pins listed as 1000V may actually have higher performance.

(8) Level listed is the passing level per EIA-JEDEC JESD22-C101E. JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process, and manufacturing with less than 250V CDM is possible if necessary precautions are taken. Pins listed as 250 V may actually have higher performance.

## **Complementary wireless module WLAN**

## Standard Laminate SiP Module

# B30911D7021Y918

R078 (WL1801) / D7021

#### 4.1.2 Recommended Operating Conditions

Rating	Condition	Sym	Min	Мах	Unit
1.8V core supply voltage			1.7	1.95	V
Vbat	DC supply range for all modes		3.4	4.3	]
IO high-level input voltage		VIH	0.65 x VDD_IO	VDD_IO	1
IO low-level input voltage		VIL	0	0.35 x VDD_IO	1
Enable inputs high-level input voltage		Vih_en	1.365	VDD_IO	
Enable inputs low-level input voltage		Vil_en	0	0.4	1
High-level output voltage	@4 mA VOH VDD_IO - 0.45 VDD_IO	VDD_IO	1		
	@ 1 mA		VDD_IO – 0.112	VDD_IO	1
	@0.3 mA		VDD_IO- 0.033	VDD_IO	1
Low-level output voltage	@4 mA	VOL	0	0.45	1
	@ 1 mA		0	0.112	1
	@0.09 mA		0	0.01	1
Input transitions time Tr/Tf from 10% to 90% (Digital IO) <sup>(1)</sup>		Tr/Tf	1	10	ns
Output rise time from 10% to 90% (Digital pins) <sup>(1)</sup>	CL <25 pF	Tr		5.3	ns
Output fall time from 10% to 90% (Digital pins) <sup>(1)</sup>	CL <25 pF	Tf		4.9	
Ambient operating temperature			-40	+85	°C

(1) Applies to all Digital lines except SDIO, SPI, UART, I2C, PCM and slow clock lines

### 4.1.3 External Digital Slow Clock Requirements (-40°C to +85°C)

The supported digital slow clock is 32.768 kHz digital (square wave). All core functions share a single input.

Characteristics	Condition	Sym	Min	Тур	Мах	Unit
Input slow clock frequency				32768		Hz
Input slow clock accuracy	WLAN, BT				±250	ppm
(initial + temp + aging)						
Input transition time Tr/Tf -IO% to 90%		Tr/Tf			100	ns
Frequency input duty cycle			15	50	85	%
Input voltage limits	Square wave, DC-coupled	ave, Vih 0.65xVDD_I			VDD_IO	Vpeak
		Vil	0		0.35xVDD_I O	-
Input impedance			1			MΩ
Input capacitance				1	5	pF

# **公TDK**

## **Complementary wireless module WLAN**

## Standard Laminate SiP Module

## B30911D7021Y918

R078 (WL1801) / D7021

#### 4.1.4 External fast clock Crystal Requirements and operation (-40°C to +85°C)

Characteristics	Condition	Min	Тур	Max	Unit
Supported frequencies		26, 38.	4	•	MHz
Frequency accuracy	Initial + temp + aging			±20	ppm
Load capacitance, $C_{L}^{(1)}$		5		13	pF
Equivalent Series Resistance, ESR				60	ohms
Drive level			100		uW

1) Load capacitance, CL = [C1.C2] / [C1 + C2] + CP, where C1, C2 are the capacitors connected on CLK\_IN\_P & CLK\_IN\_M respectively and CP is the parasitic capacitance (typically 1-2pF).

For example, for C1 = C2 = 12pF and CP = 2pF, then CL = 8pF.

#### 4.1.5 External TCXO CLK Requirements (-40°C to +85°C)

Parameter		Conditions		Min	Тур	Max	Unit
Supported frequency				26, 38.	4	•	MHz
Frequency accuracy		Total short and long	term			±20	ppm
Input voltage limits (TC	CXO_P)	Sine wave/	2.4GHz WLAN	0.2		1.4	Vр-р
		ac-coupled	5GHz WLAN	0.8		1.4	
Input impedance,	RP	Input resistance		20			kΩ
26 MHz	СР	Input capacitance				2.5	pF
Input impedance,	RP	Input resistance	Input resistance				kΩ
38.4 MHz	СР	Input capacitance				2.5	pF
Power-up time <sup>(1)</sup>	ł				5	ms	
Phase noise 2.4GHz fo	or 38.4MHz	Measured at 1 KHz			-120	dBc/Hz	
20MHz SISO <sup>(2)</sup>		Measured at 10 KH			-130	dBc/Hz	
		Measured at 100 KH			-135	dBc/Hz	
Phase noise 2.4GHz fo	or 38.4MHz	Measured at 1 KHz			-125	dBc/Hz	
40MHz SISO <sup>(2)</sup>		Measured at 10 KH	z offset			-132	dBc/Hz
			Measured at 100KHZ offset				dBc/Hz
Phase noise 5GHz for	38.4MHz,	Measured at 1 KHz			-125	dBc/Hz	
20/40MHz SISO <sup>(2)</sup>	MHz SISO <sup>(2)</sup>		Measured at 10 KHZ offset				dBc/Hz
		Measured at 100KH			-145	dBc/Hz	

(1) Power-up time is calculated from the time CLK\_REQ\_OUT asserted till the time the TCXO\_CLK amplitude is within voltage limit specified above and TCXO\_CLK frequency is within  $\pm 0.1$  ppm of final steady state frequency.

(2) The phase noise numbers listed here must be met at 38.4 MHz. For other frequencies the phase noise requirement is corrected by adding  $20 \times \log 10(f_{TCXO} / 38.4e6)$  dB. Specifically, for 26 MHz TCXO, the correction factor would be -3.4 dB.

\* The slope of the clock at zero-crossings should not be less than that of a 200 mVp-p sine-wave . i.e. 26MHz clock: 16V/µs (for 11bg band) 38.4MHz clock: 24V/µs (for 11bg band)



B30911D7021Y918 R078 (WL1801) / D7021

## **Standard Laminate SiP Module**

## 4.2 WLAN RF Performance

All specifications in this draft data sheet are design goal level and subject to change. All specifications have been measured using TDK CB (Carrier Board) and are given at the module pins (Carrier Board insertion loss is de-embedded). All measurements have been performed over VBAT voltage range from 3.4V to 4.3V and over temperature range from -40°C to +85°C.

\* 11n 40MHz bandwidth function is available. However the RF performance is guaranteed by only WL180x.

#### 4.2.1 WLAN 2.4 GHz Radio Characteristics

#### 4.2.1.1 WLAN 2.4 GHz Receiver RF Characteristics

Characteristics	Condition	Min	Тур	Max	Unit
Operation frequency range		2400		2480	MHz
Sensitivity (ANT1)	1 Mbps DSSS			-91	dBm
20MHz bandwidth.	54 Mbps OFDM			-70	
At < 10% PER limit	MCS7			-65	
Max Input Level	OFDM (11g/n)	-19			dBm
At < 10% PER limit	CCK	-4			
Adjacent Channel Rejection at	2Mbps	42.7			dB
sensitivity level +3 for OFDM and	11 Mbps	37.9			
+6 for CCK	54 Mbps	2			
LO leakage			-80		dBm

#### 4.2.1.2 WLAN 2.4 GHz Receiver Blocking Characteristics Per Band

The R078 (WL1801) / D7021 is designed to coexist with co-located cellular transmitters. Table below lists typical cellular interference sources and the corresponding maximum power from the cellular interference source that can be present at the input terminal of R078 (WL1831) / D7021, such that WLAN receiver sensitivity is not degraded by more than 1 dB. (Further improvement is achieved by antenna isolation)

Characteristics	Condition	Min	Тур	Max	Unit
Blocking performance at other bands	776 to 794 MHz (CDMA)	+10			dBm
	824 to 849 MHz (GMSK)	+10			
	824 to 849 MHz (EDGE)	+10			
	824 to 849 MHz (CDMA)	+10			
	880 to 915 MHz (GMSK)	+21			
	880 to 915 MHz (EDGE)	+21			
	1710 to 1785 MHz (GMSK)	+3			
	1710 to 1785 MHz (EDGE)	+3			
	1850 to 1910 MHz (GMSK)	-3			
	1850 to 1910 MHz (EDGE)	-3			
	1850 to 1910 MHz (CDMA)	-10			
	1850 to 1910 MHz (WCDMA)	-10			
	1920 to 1980 MHz (WCDMA)	-10			



### Standard Laminate SiP Module

B30911D7021Y918 R078 (WL1801) / D7021

#### 4.2.1.3 WLAN 2.4 GHz Transmitter power

RF transmission (Tx) tests are done in continuous transmission.

Characteristics	Condition	11bg_ANT_1 pin		
		Min	Тур	Max
Maximum output power	1 Mbps	+12	+15	
	11Mbps	+12	+15	
	6 Mbps at EVM: -10 dB,	+10	+13	
	54 Mbps at EVM: -25 dB	+9	+12	
	MCS0 (Greenfield) at	+9	+13	
	EVM: -10 dB			
	MCS7 (Greenfield) at	+8	+11	
	EVM: -28 dB			
Output power accuracy			±1.5	
Transmit power control resolution			0.125	

#### 4.2.1.4 WLAN 2.4 GHz Transmitter out-of-band emissions

Table below shows 2.4GHz WLAN transmitter out-of-band emissions for each band listed in the Condition column. The wideband noise at 2.4GHz WLAN antenna port is also listed.

Characteristics	Condition	MinTyp	Max	Unit	
Cellular bands out-of-band broadband	746 to 764 MHz (CDMA1)		-145	dBm/Hz	
emissions(1)	869 to 894 MHz (GSM850)		-145		
	925 to 960 MHz (EGSM900)		-138		
	1570 to 1580 MHz (GPS)		-142		
	1596 to 1609 MHz (GLONASS)		-130		
	1805 to 1880 MHz (DCS1800)		-140		
	1930 to 1990 MHz (PCS1900)		-120		
	2110 to 2170 MHz		-129		
Cellular bands out-of-band spurious	746 to 764 MHz (CDMA)		$-44.2^{(4)}$		
emissions	869 to 894 MHz (CDMA, GSM850)		-44.2 <sup>(4)</sup>		
	925 to 960 MHz (EGSM900)		-44.2 <sup>(4)</sup>		
	1570 to 1580 MHz (GPS)		-44.2 <sup>(4)</sup>		
	1805 to 1880 MHz (DCS1800) -44.2				
	1930 to 1990 MHz (PCS1900, CDMA)				
	2110 to 2170 MHz		-44.2 <sup>(4)</sup>		
Spurious emission during operation at	30MHz – 1GHz		-55 <sup>(2)</sup>	dBm	
1MHz RBW	2 <sup>nd</sup> harmonic		-33 <sup>(3)</sup>		
	3 <sup>rd</sup> harmonic		-33 <sup>(3)</sup>		
	4 <sup>th</sup> harmonic		-33 <sup>(3)</sup>		
	5 <sup>th</sup> harmonic		-33 <sup>(3)</sup>		

(1) Figures are for max transmission power for all available modulations. The setup noise floor is -167dBm/Hz.

(2) Based on TI IC performance

(3) ETSI limit plus 3dB margin

(4) FCC conductive limit plus 3dB margin

# **公TDK**

# **Complementary wireless module WLAN**

## Standard Laminate SiP Module

# B30911D7021Y918 R078 (WL1801) / D7021

## 4.2.1.5 2.4GHz WLAN Current Consumption

Active Current					
Spec item <sup>(1)</sup>	MIN	TYP	MAX	Units	
Tx 11CCK @15dBm		345	380	mA	
Tx 54OFDM @12dBm		290	320	mA	
Rx		65	75	mA	

(1) All measured at ANT1 and the 3.6V VBAT rail of the solution. TCXO current included.

# **⊗TDK**

**Complementary wireless module WLAN** 

### **Standard Laminate SiP Module**

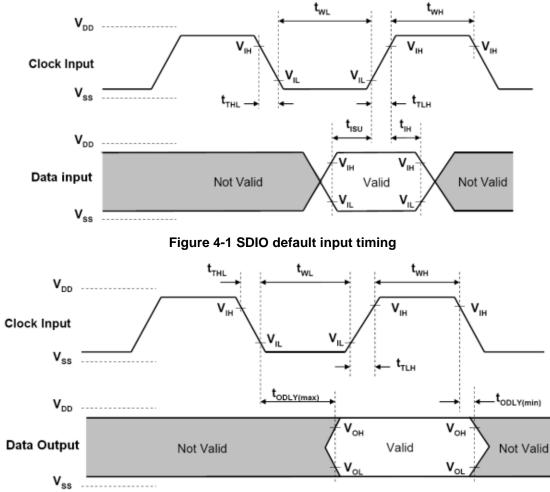
B30911D7021Y918 R078 (WL1801) / D7021

## 4.3 Interface Timing Characteristics

#### 4.3.1 SDIO timing specifications

#### 4.3.1.1 SDIO Switching Characteristics – Default rate input and output

Specification is over recommended operating conditions. Parameters are for default clock frequency.



### Figure 4-2 SDIO default output timing Table 4-1 SDIO Switching Characteristics – Deault Rate

Parameter		Min	Мах	Unit	
<sup>f</sup> clock	Clock frequency, CLK	0	26	MHz	
DC	Low/high duty cycle	40	60	%	
tTLH	Rise time, CLK		10	ns	
tthl	Fall time, CLK		10	ns	
tISU	Setup time, input valid before CLK ↑	3		ns	
t <sub>iH</sub>	Hold time, input valid after CLK ↑	2		ns	
todly	Delay time, CLK $\downarrow$ to output valid	2.5	14.8	ns	
CI	Capacitive load on outputs		15	pF	

Note: Option to change data out clock edge from falling edge (default) to rising edge, by setting configuration bit.

# **⊗TDK**

B30911D7021Y918

R078 (WL1801) / D7021

# **Complementary wireless module WLAN**

## Standard Laminate SiP Module

### 4.3.1.2 SDIO Switching Characteristics – High Rate

Specification is over recommended operating conditions. Parameters are for maximum clock frequency.

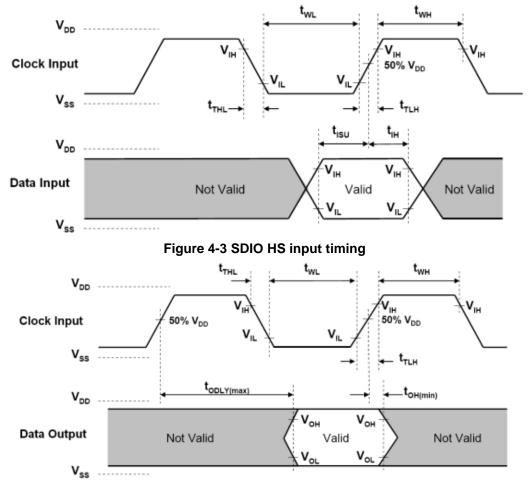


Figure 4-4 SDIO HS output timing

Paramete	r	Min	Max	Unit
clock	Clock frequency, CLK	0	50	MHz
C	Low/high duty cycle	40%	60%	
TLH	Rise time, CLK		3	ns
THL	Fall time, CLK		3	ns
ISU	Setup time, input valid before CLK ↑	3		ns
н	Hold time, input valid after CLK ↑	2		ns
ODLY	Delay time, CLK↓ to output valid	2.5	14	ns
	Capacitive load on outputs		10	pF
-				10

#### Table 4-2 SDIO Switching Characteristics – High Rate

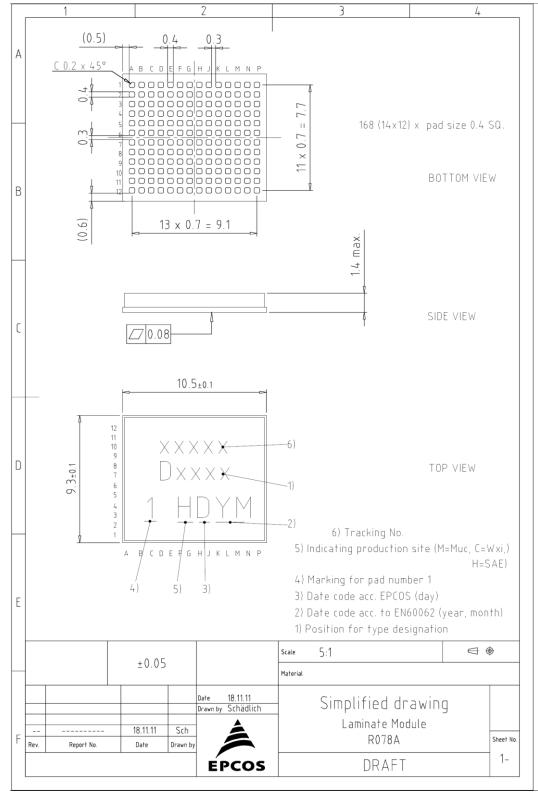


### Standard Laminate SiP Module

B30911D7021Y918 R078 (WL1801) / D7021

## 4.4 Package Mechanical Drawing

Land Grid Array (LGA) Module



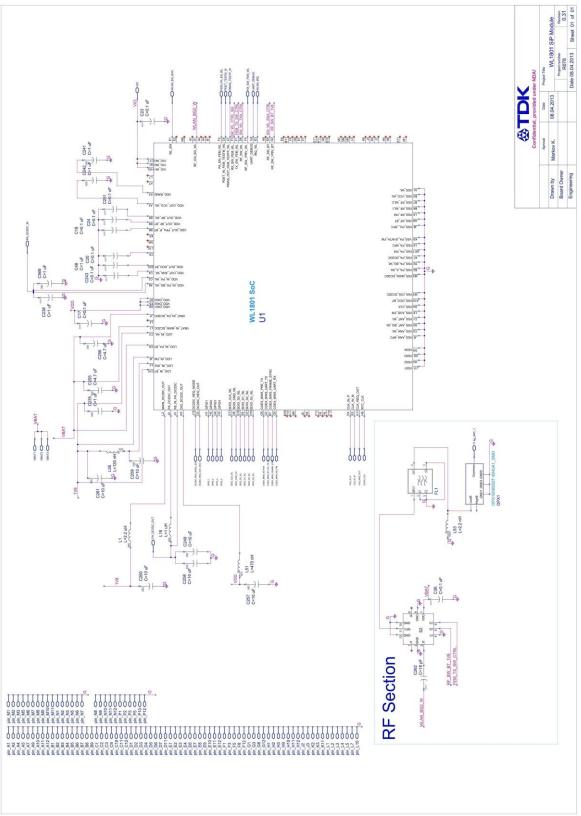


## **Standard Laminate SiP Module**

# B30911D7021Y918

R078 (WL1801) / D7021

## 4.5 Schematic





Standard Laminate SiP Module

# B30911D7021Y918 R078 (WL1801) / D7021

# 5 Lead-free Product Status

All Epcos modules in mass production are lead-free. This is achieved by using only materials with lead contamination below 1000 ppm. The applied lead-free solder alloy is the main source of Pb-contamination, which together gives Pb-levels much below 50 ppm per module.

A comprehensive qualification for these lead-free module packages has been done. The related AQTP documentation is available from Epcos on request.



B30911D7021Y918 R078 (WL1801) / D7021

tp → Тр Critical Zone T<sub>L</sub> to Tp Ramp-up Τ<sub>L</sub> Temperature Ts<sub>max</sub> Ts<sub>min</sub> Ramp-down ts Preheat 25 t 25°C to Peak ≯ Time  $\Longrightarrow$ 

# 6 Recommended Reflow Profile

**Standard Laminate SiP Module** 

Profile Feature	Range
Average Ramp-Up Rate (Ts <sub>max</sub> to Tp)	3°C/second max.
Preheat: -Temperature Min (Ts <sub>min</sub> ) -Temperature Max (Ts <sub>max</sub> ) -Time (ts <sub>min</sub> to ts <sub>max</sub> )	150°C 200°C 60-120 seconds
Time maintained above: -Temperature $(T_L)$ -Time $(t_L)$	217°C 60-150 seconds
Peak Temperature (Tp)	245-250°C
Time within 5°C of actual Peak Temperature (Tp)	20-40 seconds
Ramp-Down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

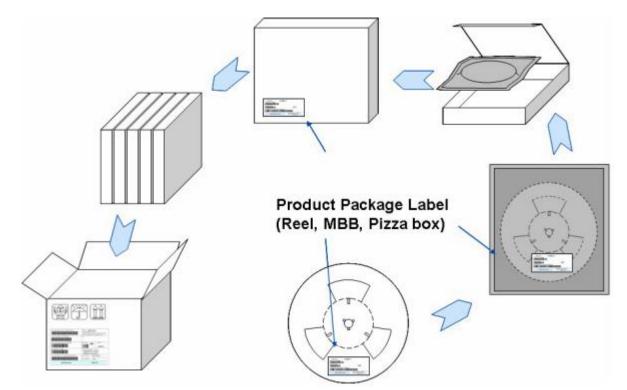


Standard Laminate SiP Module

B30911D7021Y918 R078 (WL1801) / D7021

# 7 Packing Information

## 7.1.1 Packaging flow

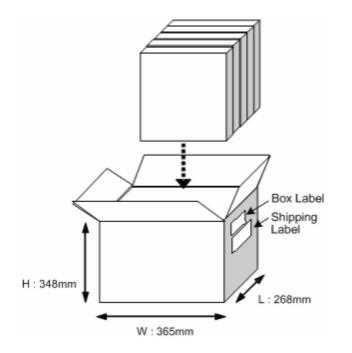




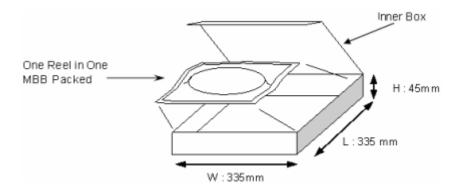
## **Standard Laminate SiP Module**

# B30911D7021Y918 R078 (WL1801) / D7021

## 7.1.2 Outer Box



#### 7.1.3 Inner Box

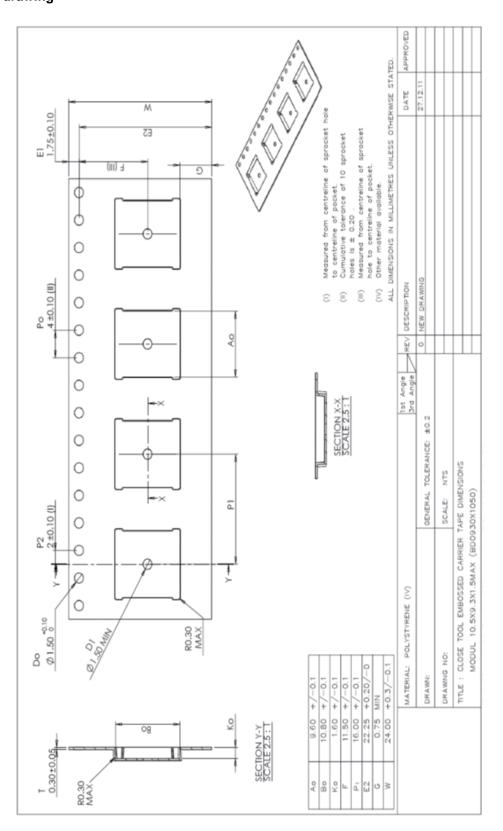




## Standard Laminate SiP Module

## B30911D7021Y918 R078 (WL1801) / D7021

# 7.1.4 Tape drawing





**Standard Laminate SiP Module** 

B30911D7021Y918

R078 (WL1801) / D7021

# 8 Revision History

	-		
Version	Date	Status	Note
1.0	27.6.2014	Official Release	Initial
1.1 3.9.2014 Official Release		Official Release	Changed 4.1.1 Absolute Maximum Ratings
1.1	3.9.2014	Official Release	Operating ambient temperature range : -15 to +55 °C
			Changed the template of the data sheet
1.2	25.9.2014	Official Release	Updated operation temperature range : -30 to +85°C
	20:0:2011		Updated 4.2.1.3 WLAN 2.4 GHz Transmitter power (1Mbps and 11Mbps)
1.3	9.12.2014	Official Release	Updated operation temperature range : -40 to +85 $^\circ\!\mathrm{C}$

## Display of ordering codes for EPCOS products

The ordering code for one and the same EPCOS product can be represented differently in data sheets, data books, other publications, on the EPCOS website, or in order-related documents such as shipping notes, order confirmations and product labels. The varying representations of the ordering codes are due to different processes employed and do not affect the specifications of the respective products. Detailed information can be found on the Internet under www.epcos.com/orderingcodes

The following applies to all products named in this publication:

- 1. Some parts of this publication contain statements about the suitability of our products for certain areas of application. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether an EPCOS product with the properties described in the product specification is suitable for use in a particular customer application.
- 2. We also point out that in individual cases, a malfunction of electronic components or failure before the end of their usual service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. In customer applications requiring a very high level of operational safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health (e.g. in accident prevention or life-saving systems), it must therefore be ensured by means of suitable design of the customer application or other action taken by the customer (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of malfunction or failure of an electronic component.
- 3. The warnings, cautions and product-specific notes must be observed.
- 4. In order to satisfy certain technical requirements, some of the products described in this publication may contain substances subject to restrictions in certain jurisdictions (e.g. because they are classed as hazardous). Useful information on this will be found in our Material Data Sheets on the Internet (www.epcos.com/material). Should you have any more detailed questions, please contact our sales offices.
- 5. We constantly strive to improve our products. Consequently, the products described in this publication may change from time to time. The same is true of the corresponding product specifications. Please check therefore to what extent product descriptions and specifications contained in this publication are still applicable before or when you place an order. We also reserve the right to discontinue production and delivery of products. Consequently, we cannot guarantee that all products named in this publication will always be available. The aforementioned does not apply in the case of individual agreements deviating from the foregoing for customer-specific products.
- 6. Unless otherwise agreed in individual contracts, all orders are subject to the current version of the "General Terms of Delivery for Products and Services in the Electrical Industry" published by the German Electrical and Electronics Industry Association (ZVEI).
- 7. The trade names EPCOS, Alu-X, CeraDiode, CeraLink, CeraPlas, CSMP, CSSP, CTVS, DeltaCap, DigiSiMic, DSSP, FilterCap, FormFit, MiniBlue, MiniCell, MKD, MKK, MLSC, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, PQSine, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SiMic, SIMID, SineFormer, SIOV, SIP5D, SIP5K, TFAP, ThermoFuse, WindCap are trademarks registered or pending in Europe and in other countries. Further information will be found on the Internet at www.epcos.com/trademarks.